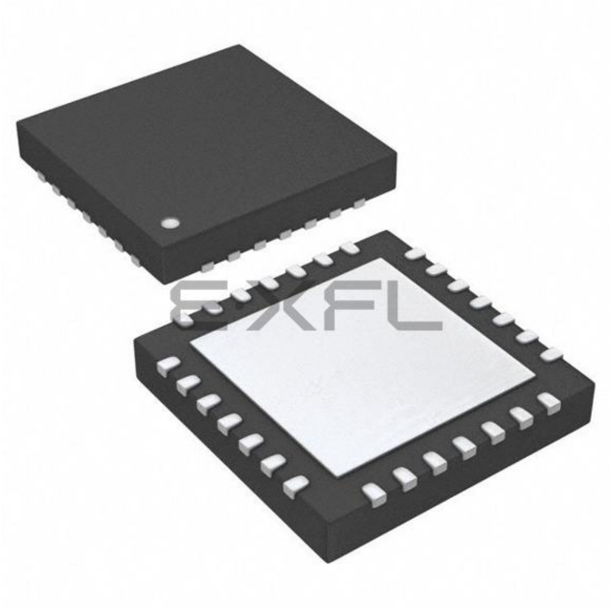

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What is "Embedded - Microcontrollers"?

"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "Embedded - Microcontrollers"

Details	
Product Status	Active
Core Processor	PIC
Core Size	8-Bit
Speed	64MHz
Connectivity	I²C, LINbus, SPI, UART/USART
Peripherals	Brown-out Detect/Reset, LVD, POR, PWM, WDT
Number of I/O	25
Program Memory Size	64KB (32K x 16)
Program Memory Type	FLASH
EEPROM Size	1K x 8
RAM Size	3.6K x 8
Voltage - Supply (Vcc/Vdd)	1.8V ~ 3.6V
Data Converters	A/D 24x10b; D/A 1x5b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	28-VQFN Exposed Pad
Supplier Device Package	28-QFN (6x6)
Purchase URL	https://www.e-xfl.com/product-detail/microchip-technology/pic18lf26k40-i-ml

3.2 Register Definitions: Configuration Words

REGISTER 3-1: Configuration Word 1L (30 0000h): Oscillators

U-1	R/W-1	R/W-1	R/W-1	U-1	R/W-1	R/W-1	R/W-1
—	RSTOSC<2:0>			—	FEXTOSC<2:0>		
bit 7							bit 0

Legend:			
R = Readable bit	W = Writable bit	U = Unimplemented bit, read as ‘1’	
-n = Value for blank device	‘1’ = Bit is set	‘0’ = Bit is cleared	x = Bit is unknown

bit 7 **Unimplemented:** Read as ‘1’

bit 6-4 **RSTOSC<2:0>:** Power-up Default Value for COSC bits
This value is the Reset default value for COSC and selects the oscillator first used by user software. Refer to COSC operation.
111 = EXTOSC operating per FEXTOSC bits (device manufacturing default)
110 = HFINTOSC with HFFRQ = 4 MHz (Register 4-5) and CDIV = 4:1 (Register 4-2)
101 = LFINTOSC
100 = SOSC
011 = Reserved
010 = EXTOSC with 4x PLL, with EXTOSC operating per FEXTOSC bits
001 = Reserved
000 = HFINTOSC with HFFRQ = 64 MHz (Register 4-5) and CDIV = 1:1 (Register 4-2). Resets COSC/NOSC to 3’b110.

bit 3 **Unimplemented:** Read as ‘1’

bit 2-0 **FEXTOSC<2:0>:** FEXTOSC External Oscillator Mode Selection bits
111 = EC (external clock) above 8 MHz; PFM set to high power (device manufacturing default)
110 = EC (external clock) for 500 kHz to 8 MHz; PFM set to medium power
101 = EC (external clock) below 500 kHz; PFM set to low power
100 = Oscillator not enabled
011 = Reserved (do not use)
010 = HS (crystal oscillator) above 8 MHz; PFM set to high power
001 = XT (crystal oscillator) above 500 kHz, below 8 MHz; PFM set to medium power
000 = LP (crystal oscillator) optimized for 32.768 kHz; PFM set to low power

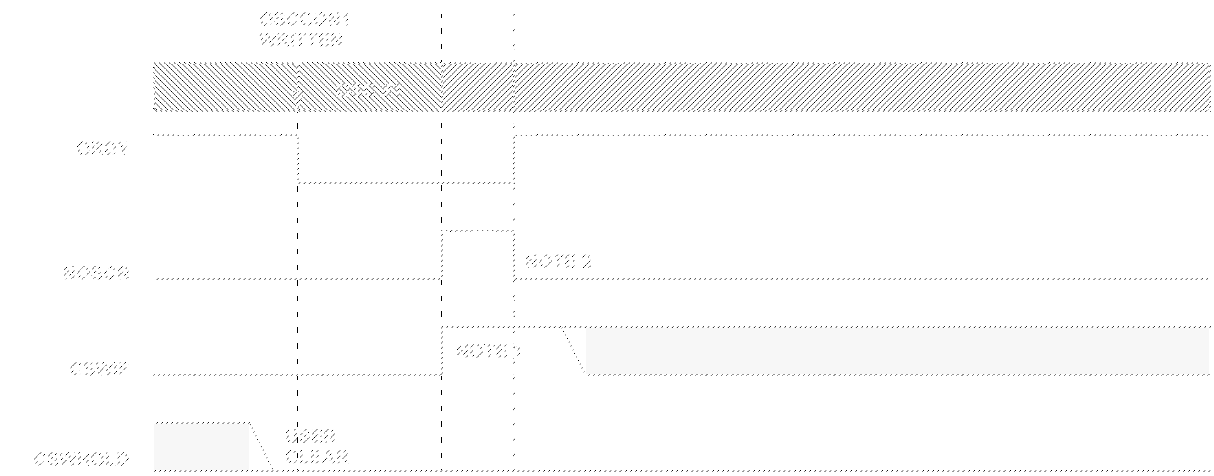
4.4.2 CLOCK SWITCH AND SLEEP

If OSCCON1 is written with a new value and the device is put to Sleep before the switch completes, the switch will not take place and the device will enter Sleep mode.

When the device wakes from Sleep and the CSWHOLD bit is clear, the device will wake with the 'new' clock active, and the clock switch interrupt flag bit (CSWIF) will be set.

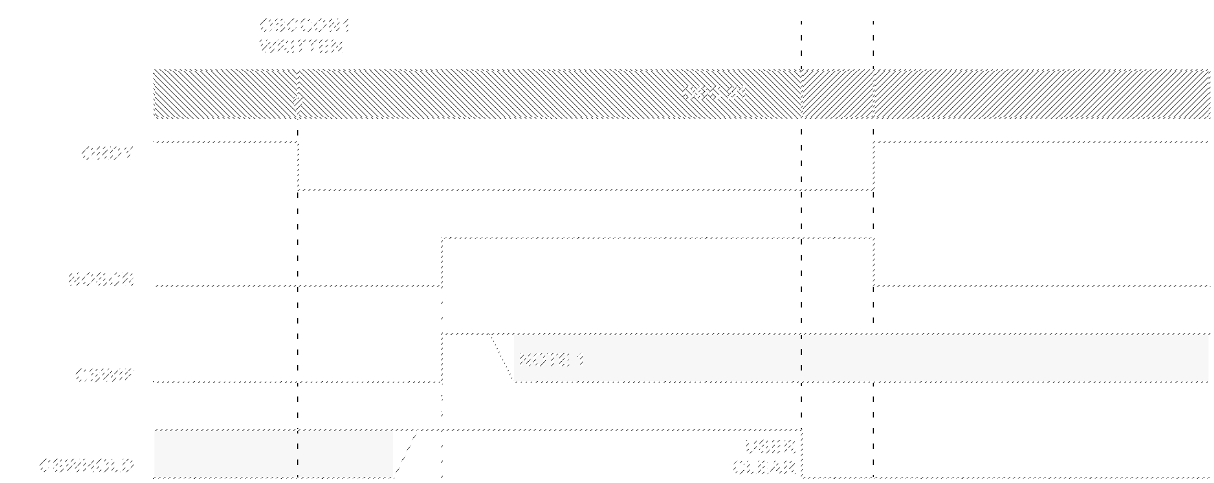
When the device wakes from Sleep and the CSWHOLD bit is set, the device will wake with the 'old' clock active and the new clock will be requested again.

FIGURE 4-6: CLOCK SWITCH (CSWHOLD = 0)



Note 1: CSWIF is asserted coincident with NOSCR; interrupt is serviced at OSC#2 speed.
2: The assertion of NOSCR is hidden from the user because it appears only for the duration of the switch.

FIGURE 4-7: CLOCK SWITCH (CSWHOLD = 1)

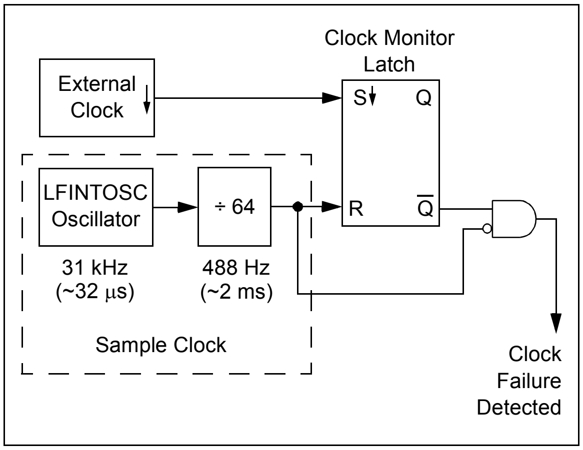


Note 1: CSWIF is asserted coincident with NOSCR, and may be cleared before or after clearing CSWHOLD = 0.

4.5 Fail-Safe Clock Monitor

The Fail-Safe Clock Monitor (FSCM) allows the device to continue operating should the external oscillator fail. The FSCM is enabled by setting the FCMEN bit in the Configuration Words. The FSCM is applicable to all external Oscillator modes (LP, XT, HS, ECL/M/H and Secondary Oscillator).

FIGURE 4-9: FSCM BLOCK DIAGRAM



4.5.1 FAIL-SAFE DETECTION

The FSCM module detects a failed oscillator by comparing the external oscillator to the FSCM sample clock. The sample clock is generated by dividing the LFINTOSC by 64. See Figure 4-9. Inside the fail detector block is a latch. The external clock sets the latch on each falling edge of the external clock. The sample clock clears the latch on each rising edge of the sample clock. A failure is detected when an entire half-cycle of the sample clock elapses before the external clock goes low.

4.5.2 FAIL-SAFE OPERATION

When the external clock fails, the FSCM overwrites the COSC bits to select HFINTOSC (`3'b110`). The frequency of HFINTOSC would be determined by the previous state of the HFFRQ bits and the NDIV/CDIV bits. The bit flag OSCFIF of the PIR1 register is set. Setting this flag will generate an interrupt if the OSCFIE bit of the PIE1 register is also set. The device firmware can then take steps to mitigate the problems that may arise from a failed clock. The system clock will continue to be sourced from the internal clock source until the device firmware successfully restarts the external oscillator and switches back to external operation, by writing to the NOSC and NDIV bits of the OSCCON1 register.

4.5.3 FAIL-SAFE CONDITION CLEARING

The Fail-Safe condition is cleared after a Reset, executing a `SLEEP` instruction or changing the NOSC and NDIV bits of the OSCCON1 register. When switching to the external oscillator or PLL, the OST is restarted. While the OST is running, the device continues to operate from the INTOSC selected in OSCCON1. When the OST times out, the Fail-Safe condition is cleared after successfully switching to the external clock source. The OSCFIF bit should be cleared prior to switching to the external clock source. If the Fail-Safe condition still exists, the OSCFIF flag will again become set by hardware.

10.7.3 MAPPING THE ACCESS BANK IN INDEXED LITERAL OFFSET MODE

The use of Indexed Literal Offset Addressing mode effectively changes how the first 96 locations of Access RAM (00h to 5Fh) are mapped. Rather than containing just the contents of the bottom section of Bank 0, this mode maps the contents from a user defined "window" that can be located anywhere in the data memory space. The value of FSR2 establishes the lower boundary of the addresses mapped into the window, while the upper boundary is defined by FSR2 plus 95 (5Fh). Addresses in the Access RAM above 5Fh are mapped as previously described (see **Section 10.4.2 "Access Bank"**). An example of Access Bank remapping in this addressing mode is shown in Figure 10-8.

Remapping of the Access Bank applies *only* to operations using the Indexed Literal Offset mode. Operations that use the BSR (Access RAM bit is '1') will continue to use direct addressing as before.

10.8 PIC18 Instruction Execution and the Extended Instruction Set

Enabling the extended instruction set adds eight additional commands to the existing PIC18 instruction set. These instructions are executed as described in **Section 35.2 "Extended Instruction Set"**.

FIGURE 10-8: REMAPPING THE ACCESS BANK WITH INDEXED LITERAL OFFSET ADDRESSING

Example Situation:

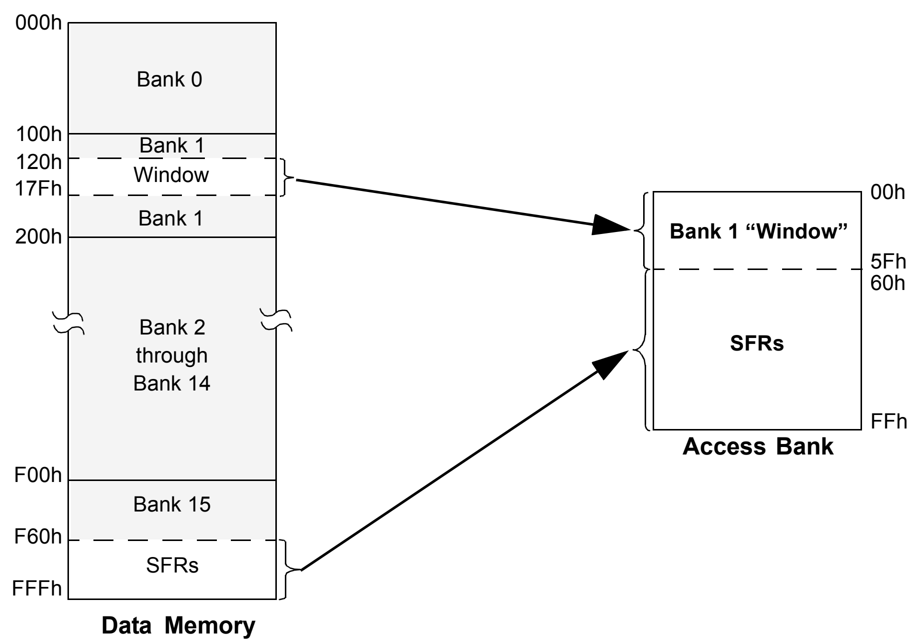
`ADDWF f, d, a`

FSR2H:FSR2L = 120h

Locations in the region from the FSR2 pointer (120h) to the pointer plus 05Fh (17Fh) are mapped to the bottom of the Access RAM (000h-05Fh).

Special File Registers at F60h through FFFh are mapped to 60h through FFh, as usual.

Bank 0 addresses below 5Fh can still be addressed by using the BSR.



11.1.4 NVM UNLOCK SEQUENCE

The unlock sequence is a mechanism that protects the NVM from unintended self-write programming or erasing. The sequence must be executed and completed without interruption to successfully complete any of the following operations:

- PFM Row Erase
- Write of PFM write latches to PFM memory
- Write of PFM write latches to User IDs
- Write to Data EEPROM Memory
- Write to Configuration Words

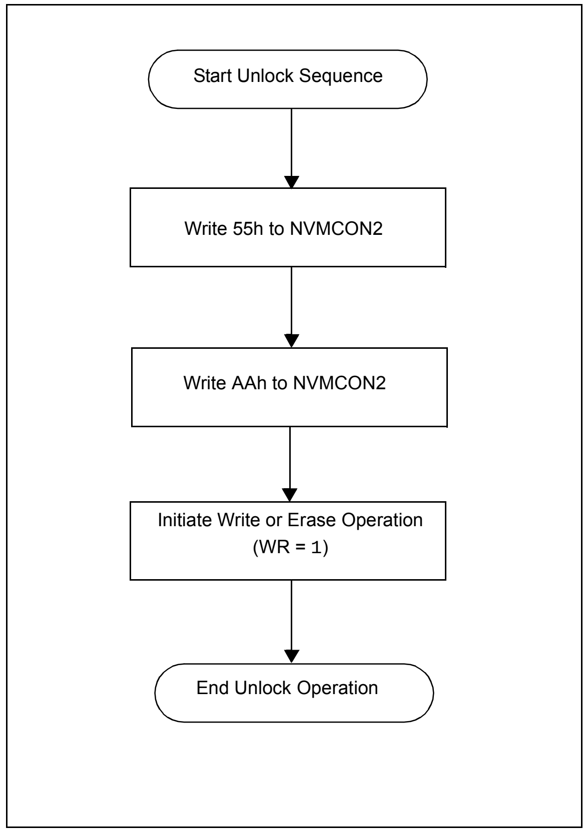
The unlock sequence consists of the following steps and must be completed in order:

- Write 55h to NVMCON2
- Write AAh to NMVCON2
- Set the WR bit of NVMCON1

Once the WR bit is set, the processor will stall internal operations until the operation is complete and then resume with the next instruction.

Since the unlock sequence must not be interrupted, global interrupts should be disabled prior to the unlock sequence and re-enabled after the unlock sequence is completed.

FIGURE 11-6: NVM UNLOCK SEQUENCE FLOWCHART



EXAMPLE 11-2: NVM UNLOCK SEQUENCE

```
BCF        INTCON,GIE     ; Recommended so sequence is not interrupted
BANKSEL    NVMCON1
BSF        NVMCON1,WREN   ; Enable write/erase
MOVLW      55h            ; Load 55h

MOVWF      NVMCON2        ; Step 1: Load 55h into NVMCON2
MOVLW      AAh            ; Step 2: Load W with AAh
MOVWF      NVMCON2        ; Step 3: Load AAh into NVMCON2
BSF        INTCON1,WR     ; Step 4: Set WR bit to begin write/erase

BSF        INTCON,GIE     ; Re-enable interrupts
```

Note 1: Sequence begins when NVMCON2 is written; steps 1-4 must occur in the cycle-accurate order shown. If the timing of the steps 1 to 4 is corrupted by an interrupt or a debugger Halt, the action will not take place.

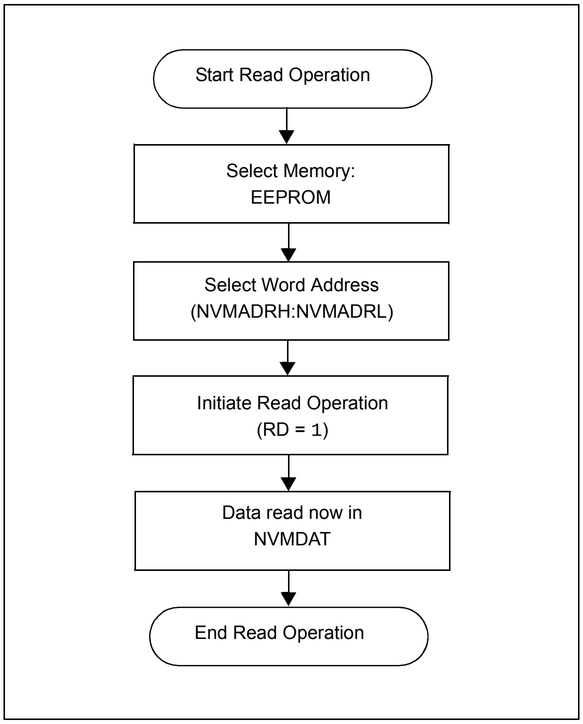
2: Opcodes shown are illustrative; any instruction that has the indicated effect may be used.

11.3.3 READING THE DATA EEPROM MEMORY

To read a data memory location, the user must write the address to the NVMADRL and NVMADRH register pair, clear NVMREG<1:0> control bit in NVMCON1 register to access Data EEPROM locations and then set control bit, RD. The data is available on the very next instruction cycle; therefore, the NVMDAT register can be read by the next instruction. NVMDAT will hold this value until another read operation, or until it is written to by the user (during a write operation).

The basic process is shown in Example 11-5.

FIGURE 11-11: DATA EEPROM READ FLOWCHART



11.3.4 WRITING TO THE DATA EEPROM MEMORY

To write an EEPROM data location, the address must first be written to the NVMADRL and NVMADRH register pair and the data written to the NVMDAT register. The sequence in Example 11-6 must be followed to initiate the write cycle.

The write will not begin if NVM Unlock sequence, described in **Section 11.1.4 "NVM Unlock Sequence"**, is not exactly followed for each byte. It is strongly recommended that interrupts be disabled during this code segment.

Additionally, the WREN bit in NVMCON1 must be set to enable writes. This mechanism prevents accidental writes to data EEPROM due to unexpected code execution (i.e., runaway programs). The WREN bit should be kept clear at all times, except when updating the EEPROM. The WREN bit is not cleared by hardware.

After a write sequence has been initiated, NVMCON1, NVMADRL, NVMADRH and NVMDAT cannot be modified. The WR bit will be inhibited from being set unless the WREN bit is set. Both WR and WREN cannot be set with the same instruction.

After a write sequence has been initiated, clearing the WREN bit will not affect this write cycle. A single Data EEPROM word is written and the operation includes an implicit erase cycle for that word (it is not necessary to set FREE). CPU execution continues in parallel and at the completion of the write cycle, the WR bit is cleared in hardware and the NVM Interrupt Flag bit (NVMIF) is set. The user can either enable this interrupt or poll this bit. NVMIF must be cleared by software.

REGISTER 14-10: PIE0: PERIPHERAL INTERRUPT ENABLE REGISTER 0

U-0	U-0	R/W-0/0	R/W-0/0	U-0	R/W-0/0	R/W-0/0	R/W-0/0
—	—	TMR0IE(1)	IOCIE(1)	—	INT2IE(1)	INT1IE(1)	INT0IE(1)
bit 7							bit 0

Legend: IE			
R = Readable bit	W = Writable bit	U = Unimplemented bit, read as ‘0’	
-n = Value at POR	‘1’ = Bit is set	‘0’ = Bit is cleared	x = Bit is unknown

bit 7-6 **Unimplemented:** Read as ‘0’

bit 5 **TMR0IE:** Timer0 Interrupt Enable bit(1)
1 = Enabled
0 = Disabled

bit 4 **IOCIE:** Interrupt-on-Change Enable bit(1)
1 = Enabled
0 = Disabled

bit 3 **Unimplemented:** Read as ‘0’

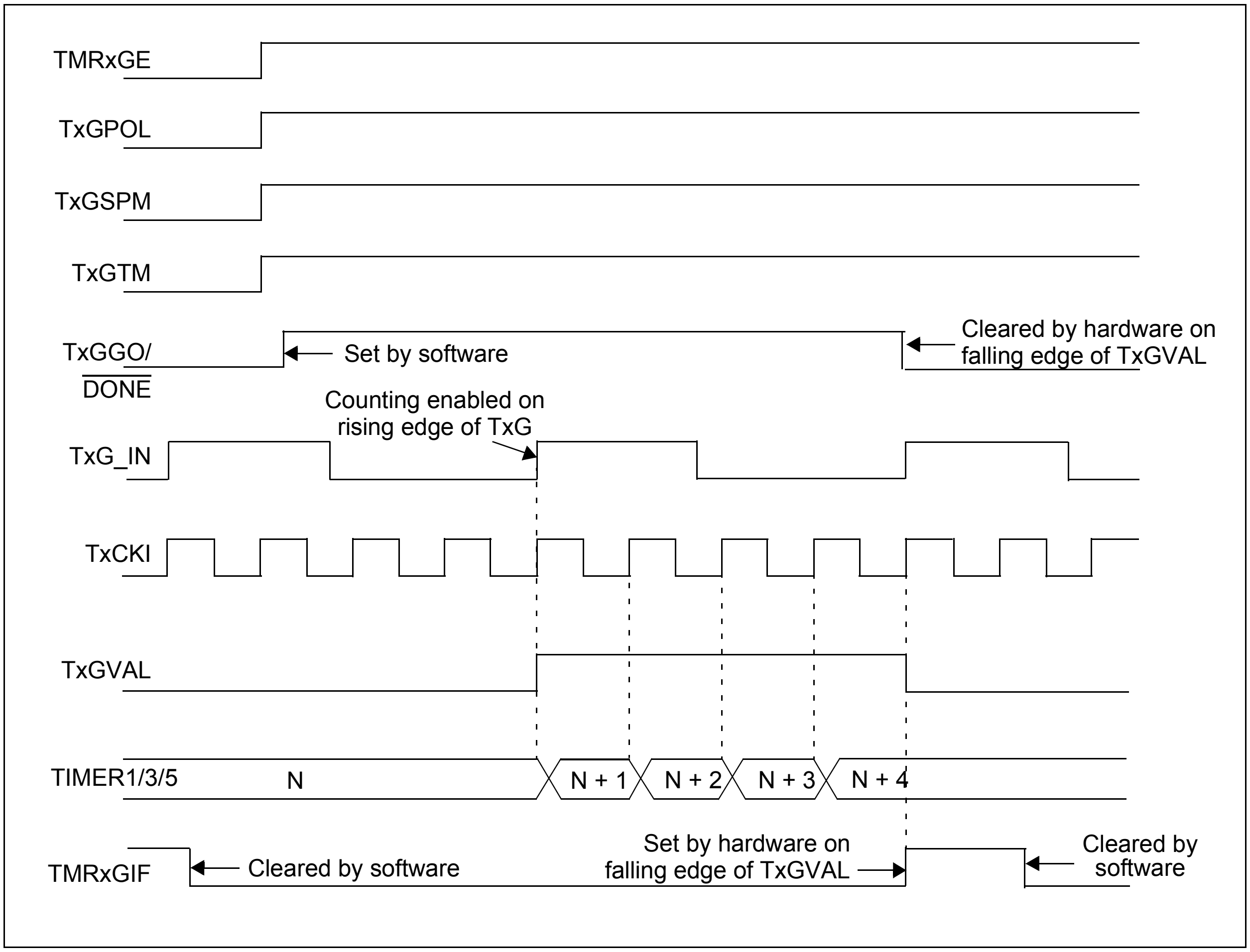
bit 2 **INT2IE:** External Interrupt 2 Enable bit(1)
1 = Enabled
0 = Disabled

bit 1 **INT1IE:** External Interrupt 1 Enable bit(1)
1 = Enabled
0 = Disabled

bit 0 **INT0IE:** External Interrupt 0 Enable bit(1)
1 = Enabled
0 = Disabled

Note 1: PIR0 interrupts are not disabled by the PEIE bit in the INTCON register. are not disabled by the PEIE bit in the INTCON register.

FIGURE 19-7: TIMER1/3/5 GATE SINGLE-PULSE AND TOGGLE COMBINED MODE



19.13 Peripheral Module Disable

When a peripheral module is not used or inactive, the module can be disabled by setting the Module Disable bit in the PMD registers. This will reduce power consumption to an absolute minimum. Setting the PMD bits holds the module in Reset and disconnects the module's clock source. The Module Disable bits for Timer1 (TMR1MD), Timer3 (TMR3MD) and Timer5 (TMR5MD) are in the PMD1 register. See **Section 7.0 "Peripheral Module Disable (PMD)"** for more information.

20.5.10 LEVEL-TRIGGERED HARDWARE LIMIT ONE-SHOT MODES

The Level-Triggered Hardware Limit One-Shot modes hold the timer in Reset on an external Reset level and start counting when both the ON bit is set and the external signal is not at the Reset level. If one of either the external signal is not in Reset or the ON bit is set then the other signal being set/made active will start the timer. Reset levels are selected as follows:

- Low Reset level (MODE<4:0> = `10110`)
- High Reset level (MODE<4:0> = `10111`)

When the timer count matches the PRx period count, the timer is reset and the ON bit is cleared. When the ON bit is cleared by either a PRx match or by software control the timer will stay in Reset until both the ON bit is set and the external signal is not at the Reset level.

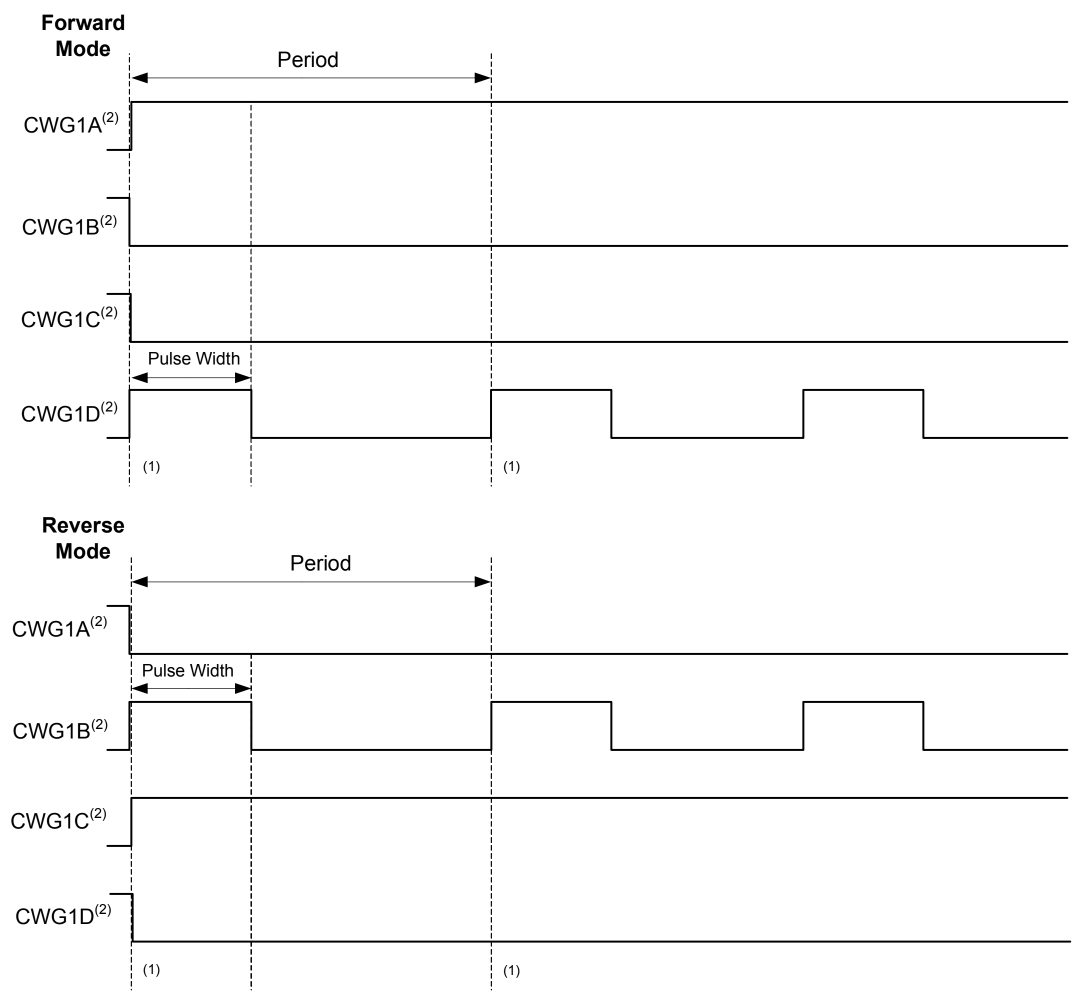
When Level-Triggered Hardware Limit One-Shot modes are used in conjunction with the CCP PWM operation the PWM drive goes active with either the external signal edge or the setting of the ON bit, whichever of the two starts the timer.

In Forward Full-Bridge mode (MODE<2:0> = `010`), CWG1A is driven to its active state, CWG1B and CWG1C are driven to their inactive state, and CWG1D is modulated by the input signal, as shown in Figure 24-7.

In Reverse Full-Bridge mode (MODE<2:0> = `011`), CWG1C is driven to its active state, CWG1A and CWG1D are driven to their inactive states, and CWG1B is modulated by the input signal, as shown in Figure 24-7.

In Full-Bridge mode, the dead-band period is used when there is a switch from forward to reverse or vice-versa. This dead-band control is described in **Section 24.6 "Dead-Band Control"**, with additional details in **Section 24.7 "Rising Edge and Reverse Dead Band"** and **Section 24.8 "Falling Edge and Forward Dead Band"**. Steering modes are not used with either of the Full-Bridge modes. The mode selection may be toggled between forward and reverse toggling the MODE<0> bit of the CWG1CON0 while keeping MODE<2:1> static, without disabling the CWG module.

FIGURE 24-7: EXAMPLE OF FULL-BRIDGE OUTPUT



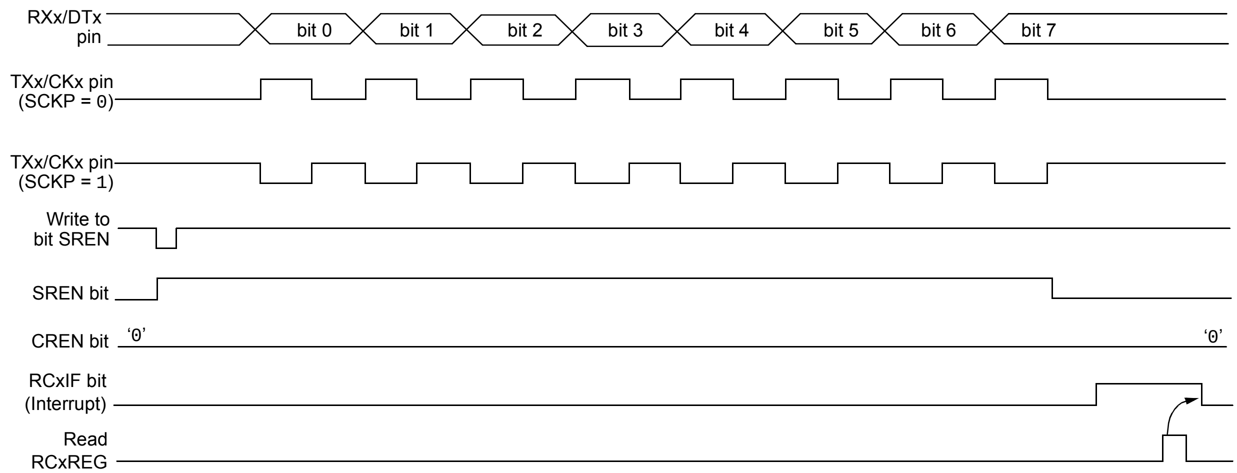
Note 1: A rising CWG data input creates a rising event on the modulated output.
2: Output signals shown as active-high; all POLy bits are clear.

TABLE 24-3: SUMMARY OF REGISTERS ASSOCIATED WITH CWG

Name	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	Register on Page
CWG1CON0	EN	LD	—	—	—	MODE<2:0>			315
CWG1CON1	—	—	IN	—	POLD	POLC	POLB	POLA	316
CWG1CLKCON	—	—	—	—	—	—	—	CS	317
CWG1ISM	—	—	—	—	—	ISM<2:0>			317
CWG1STR	OVRD	OVRC	OVRB	OVRA	STRD	STRC	STRB	STRA	318
CWG1AS0	SHUTDOWN	REN	LSBD<1:0>		LSAC<1:0>		—	—	319
CWG1AS1	—	—	AS5E	AS4E	AS3E	AS2E	AS1E	AS0E	320
CWG1DBR	—	—	DBR<5:0>						321
CWG1DBF	—	—	DBF<5:0>						321
PIE7	SCANIE	CRCIE	NVMIE	—	—	—	—	CWG1IE	186
PIR7	SCANIF	CRCIF	NVMIF	—	—	—	—	CWG1IF	178
IPR7	SCANIP	CRCIP	NVMIP	—	—	—	—	CWG1IP	194
PMD4	UART2MD	UART1MD	MSSP2MD	MSSP1MD	—	—	—	CWG1MD	72

Legend: – = unimplemented locations read as ‘0’. Shaded cells are not used by CWG.

FIGURE 27-12: SYNCHRONOUS RECEPTION (MASTER MODE, SREN)



Note: Timing diagram demonstrates Sync Master mode with bit SREN = 1 and bit BRGH = 0.

TABLE 27-8: SUMMARY OF REGISTERS ASSOCIATED WITH SYNCHRONOUS MASTER RECEPTION

Name	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	Register on Page
ANSELB	ANSELB7	ANSELB6	ANSELB5	ANSELB4	ANSELB3	ANSELB2	ANSELB1	ANSELB0	204
ANSELC	ANSELC7	ANSELC6	ANSELC5	ANSELC4	ANSELC3	ANSELC2	ANSELC1	ANSELC0	204
BAUDxCON	ABDOVF	RCIDL	—	SCKP	BRG16	—	WUE	ABDEN	395
INTCON	GIE/GIEH	PEIE/GIEL	IPEN	—	—	INT2EDG	INT1EDG	INT0EDG	170
PIE3	RC2IE	TX2IE	RC1IE	TX1IE	BCL2IE	SSP2IE	BCL1IE	SSP1IE	182
PIR3	RC2IF	TX2IF	RC1IF	TX1IF	BCL2IF	SSP2IF	BCL1IF	SSP1IF	174
IPR3	RC2IP	TX2IP	RC1IP	TX1IP	BCL2IP	SSP2IP	BCL1IP	SSP1IP	190
RCxREG	EUSARTx Receive Data Register								399*
RCxSTA	SPEN	RX9	SREN	CREN	ADDEN	FERR	OERR	RX9D	394
RxyPPS	—	—	—	RxyPPS<4:0>					218
RXxPPS	—	—	—	RXPPS<4:0>					216
SPxBRGH	EUSARTx Baud Rate Generator, High Byte								404*
SPxBRGL	EUSARTx Baud Rate Generator, Low Byte								404*
TXxSTA	CSRC	TX9	TXEN	SYNC	SENDB	BRGH	TRMT	TX9D	393

Legend: — = unimplemented location, read as '0'. Shaded cells are not used for synchronous master reception.
* Page provides register information.

31.1.3 ADC VOLTAGE REFERENCE

The ADPREF<1:0> bits of the ADREF register provide control of the positive voltage reference. The positive voltage reference can be:

- VREF+ pin
- VDD
- FVR 1.024V
- FVR 2.048V
- FVR 4.096V

The ADNREF bit of the ADREF register provides control of the negative voltage reference. The negative voltage reference can be:

- VREF- pin
- VSS

See **Section 28.0 "Fixed Voltage Reference (FVR)"** for more details on the Fixed Voltage Reference.

31.1.4 CONVERSION CLOCK

The source of the conversion clock is software selectable via the ADCLK register and the ADCS bits of the ADCON0 register. There are 66 possible clock options:

- FOSC/2
- FOSC/4
- FOSC/6
- FOSC/8
- FOSC/10

  .
  .
  .

- FOSC/128
- FRC (dedicated RC oscillator)

The time to complete one bit conversion is defined as TAD. One full 10-bit conversion requires 11.5 TAD periods as shown in Figure 31-2.

For correct conversion, the appropriate TAD specification must be met. Refer to Table 37-14 for more information. Table 31-1 gives examples of appropriate ADC clock selections.

Note 1:	Unless using the FRC, any changes in the system clock frequency will change the ADC clock frequency, which may adversely affect the ADC result.
2:	The internal control logic of the ADC runs off of the clock selected by the ADCS bit of ADCON0. What this can mean is when the ADCS bit of ADCON0 is set to '1' (ADC runs on FRC), there may be unexpected delays in operation when setting ADC control bits.

DAW — Decimal Adjust W Register

Syntax:	DAW
Operands:	None

Operation:	If [W<3:0> > 9] or [DC = 1] then
	(W<3:0>) + 6 → W<3:0>;
	else
	(W<3:0>) → W<3:0>;
	
	If [W<7:4> + DC > 9] or [C = 1] then
	(W<7:4>) + 6 + DC → W<7:4> ;
	else
	(W<7:4>) + DC → W<7:4>

Status Affected:	C
Encoding:	`0000` `0000` `0000` `0111`
Description:	`DAW` adjusts the 8-bit value in W, resulting from the earlier addition of two variables (each in packed BCD format) and produces a correct packed BCD result.
Words:	1
Cycles:	1

Q Cycle Activity:

Q1	Q2	Q3	Q4
Decode	Read register W	Process Data	Write W

Example1:

`DAW`

Before Instruction

W = A5h
C = 0
DC = 0

After Instruction

W = 05h
C = 1
DC = 0

Example 2:

Before Instruction

W = CEh
C = 0
DC = 0

After Instruction

W = 34h
C = 1
DC = 0

DECF — Decrement f

Syntax:	DECF f {,d {,a}}
Operands:	$0 \leq f \leq 255$ $d \in [0,1]$ $a \in [0,1]$
Operation:	(f) – 1 → dest
Status Affected:	C, DC, N, OV, Z
Encoding:	`0000` `01da` `ffff` `ffff`
Description:	Decrement register ‘f’. If ‘d’ is ‘`0`’, the result is stored in W. If ‘d’ is ‘`1`’, the result is stored back in register ‘f’ (default). If ‘a’ is ‘`0`’, the Access Bank is selected. If ‘a’ is ‘`1`’, the BSR is used to select the GPR bank. If ‘a’ is ‘`0`’ and the extended instruction set is enabled, this instruction operates in Indexed Literal Offset Addressing mode whenever $f \leq 95$ (5Fh). See **Section 35.2.3 “Byte-Oriented and Bit-Oriented Instructions in Indexed Literal Offset Mode”** for details.
Words:	1
Cycles:	1

Q Cycle Activity:

Q1	Q2	Q3	Q4
Decode	Read register ‘f’	Process Data	Write to destination

Example: `DECF CNT, 1, 0`

Before Instruction

CNT = 01h
Z = 0

After Instruction

CNT = 00h
Z = 1

RETURN — Return from Subroutine

Syntax:	RETURN {s}
Operands:	s ∈ [0,1]
Operation:	(TOS) → PC, if s = `1` (WS) → W, (STATUSS) → Status, (BSRS) → BSR, PCLATU, PCLATH are unchanged
Status Affected:	None
Encoding:	`0000` `0000` `0001` `001s`
Description:	Return from subroutine. The stack is popped and the top of the stack (TOS) is loaded into the program counter. If 's'= `1`, the contents of the shadow registers, WS, STATUSS and BSRS, are loaded into their corresponding registers, W, Status and BSR. If 's' = `0`, no update of these registers occurs (default).
Words:	1
Cycles:	2

Q Cycle Activity:

Q1	Q2	Q3	Q4
Decode	No operation	Process Data	POP PC from stack
No operation	No operation	No operation	No operation

Example: `RETURN`

After Instruction:
PC = TOS

RLCF — Rotate Left f through Carry

Syntax:	RLCF f {,d {,a}}
Operands:	0 ≤ f ≤ 255 d ∈ [0,1] a ∈ [0,1]
Operation:	(f<n>) → dest<n + 1>, (f<7>) → C, (C) → dest<0>
Status Affected:	C, N, Z
Encoding:	`0011` `01da` `ffff` `ffff`
Description:	The contents of register 'f' are rotated one bit to the left through the CARRY flag. If 'd' is '`0`', the result is placed in W. If 'd' is '`1`', the result is stored back in register 'f' (default). If 'a' is '`0`', the Access Bank is selected. If 'a' is '`1`', the BSR is used to select the GPR bank. If 'a' is '`0`' and the extended instruction set is enabled, this instruction operates in Indexed Literal Offset Addressing mode whenever f ≤ 95 (5Fh). See **Section 35.2.3 "Byte-Oriented and Bit-Oriented Instructions in Indexed Literal Offset Mode"** for details.

Words:	1
Cycles:	1

Q Cycle Activity:

Q1	Q2	Q3	Q4
Decode	Read register 'f'	Process Data	Write to destination

Example: `RLCF REG, 0, 0`

Before Instruction
```
REG  =  1110 0110
C    =  0
```
After Instruction
```
REG  =  1110 0110
W    =  1100 1100
C    =  1
```

XORWF	**Exclusive OR W with f**
Syntax:	XORWF f {,d {,a}}
Operands:	$0 \leq f \leq 255$ $d \in [0,1]$ $a \in [0,1]$
Operation:	(W) .XOR. (f) $\rightarrow$ dest
Status Affected:	N, Z
Encoding:	`0001` `10da` `ffff` `ffff`
Description:	Exclusive OR the contents of W with register 'f'. If 'd' is '0', the result is stored in W. If 'd' is '1', the result is stored back in the register 'f' (default). If 'a' is '0', the Access Bank is selected. If 'a' is '1', the BSR is used to select the GPR bank. If 'a' is '0' and the extended instruction set is enabled, this instruction operates in Indexed Literal Offset Addressing mode whenever $f \leq 95$ (5Fh). See **Section 35.2.3 "Byte-Oriented and Bit-Oriented Instructions in Indexed Literal Offset Mode"** for details.
Words:	1
Cycles:	1

Q Cycle Activity:

Q1	Q2	Q3	Q4
Decode	Read register 'f'	Process Data	Write to destination

Example: `XORWF REG, 1, 0`

Before Instruction
REG = AFh
W = B5h
After Instruction
REG = 1Ah
W = B5h

TABLE 37-7: EXTERNAL CLOCK/OSCILLATOR TIMING REQUIREMENTS (CONTINUED)

Standard Operating Conditions (unless otherwise stated)							
Param No.	**Sym.**	**Characteristic**	**Min.**	**Typ†**	**Max.**	**Units**	**Conditions**
OS21	F_{CY}	Instruction Frequency	—	FOSC/4	—	MHz	
OS22	T_{CY}	Instruction Period	62.5	$1/F_{CY}$	—	ns	

* These parameters are characterized but not tested.

† Data in “Typ” column is at 3.0V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

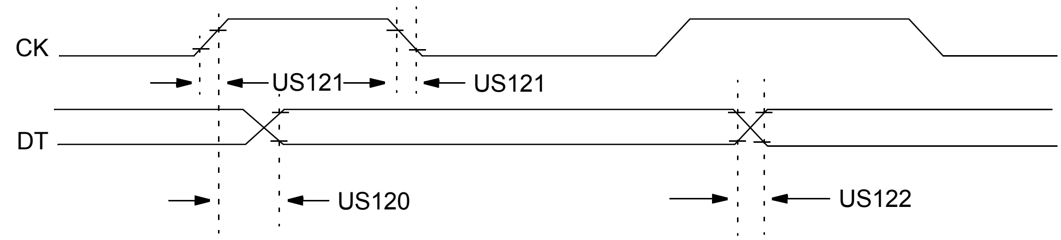
Note 1: Instruction cycle period (TCY) equals four times the input oscillator time base period. All specified values are based on characterization data for that particular oscillator type under standard operating conditions with the device executing code. Exceeding these specified limits may result in an unstable oscillator operation and/or higher than expected current consumption. All devices are tested to operate at “min” values with an external clock applied to OSC1 pin. When an external clock input is used, the “max” cycle time limit is “DC” (no clock) for all devices.

2: The system clock frequency (FOSC) is selected by the “main clock switch controls” as described in **Section 6.0 “Power-Saving Operation Modes”**.

3: The system clock frequency (FOSC) must meet the voltage requirements defined in the **Section 37.2 “Standard Operating Conditions”**.

4: LP, XT and HS oscillator modes require an appropriate crystal or resonator to be connected to the device. For clocking the device with the external square wave, one of the EC mode selections must be used.

FIGURE 37-14: EUSART SYNCHRONOUS TRANSMISSION (MASTER/SLAVE) TIMING

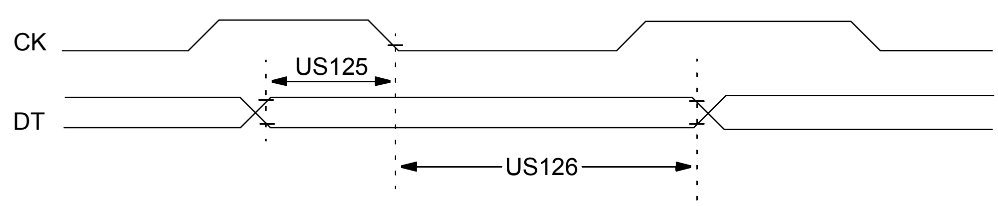


Note: Refer to Figure 37-4 for load conditions.

TABLE 37-21: EUSART SYNCHRONOUS TRANSMISSION REQUIREMENTS

Standard Operating Conditions (unless otherwise stated)						
Param. No.	**Symbol**	**Characteristic**	**Min.**	**Max.**	**Units**	**Conditions**
US120	TCKH2DTV	SYNC XMIT (Master and Slave) Clock high to data-out valid	—	80	ns	3.0V ≤ VDD ≤ 5.5V
			—	100	ns	1.8V ≤ VDD ≤ 5.5V
US121	TCKRF	Clock out rise time and fall time (Master mode)	—	45	ns	3.0V ≤ VDD ≤ 5.5V
			—	50	ns	1.8V ≤ VDD ≤ 5.5V
US122	TDTRF	Data-out rise time and fall time	—	45	ns	3.0V ≤ VDD ≤ 5.5V
			—	50	ns	1.8V ≤ VDD ≤ 5.5V

FIGURE 37-15: EUSART SYNCHRONOUS RECEIVE (MASTER/SLAVE) TIMING



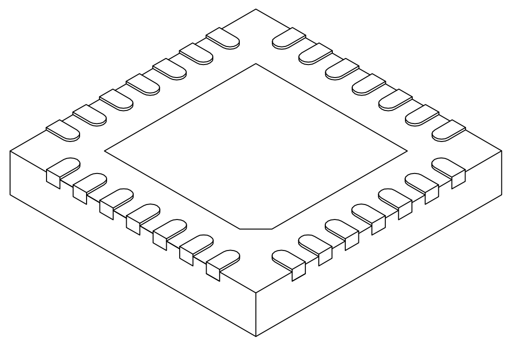
Note: Refer to Figure 37-4 for load conditions.

TABLE 37-22: EUSART SYNCHRONOUS RECEIVE REQUIREMENTS

Standard Operating Conditions (unless otherwise stated)						
Param. No.	**Symbol**	**Characteristic**	**Min.**	**Max.**	**Units**	**Conditions**
US125	TDTV2CKL	SYNC RCV (Master and Slave) Data-setup before CK ↓ (DT hold time)	10	—	ns	
US126	TCKL2DTL	Data-hold after CK ↓ (DT hold time)	15	—	ns	

28-Lead Plastic Quad Flat, No Lead Package (ML) - 6x6 mm Body [QFN] With 0.55 mm Terminal Length

Note:	For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



Units		MILLIMETERS		
Dimension	Limits	MIN	NOM	MAX
Number of Pins	N		28	
Pitch	e		0.65 BSC	
Overall Height	A	0.80	0.90	1.00
Standoff	A1	0.00	0.02	0.05
Terminal Thickness	A3		0.20 REF	
Overall Width	E		6.00 BSC	
Exposed Pad Width	E2	3.65	3.70	4.20
Overall Length	D		6.00 BSC	
Exposed Pad Length	D2	3.65	3.70	4.20
Terminal Width	b	0.23	0.30	0.35
Terminal Length	L	0.50	0.55	0.70
Terminal-to-Exposed Pad	K	0.20	-	-

Notes:

1. Pin 1 visual index feature may vary, but must be located within the hatched area.
2. Package is saw singulated
3. Dimensioning and tolerancing per ASME Y14.5M.
   BSC: Basic Dimension. Theoretically exact value shown without tolerances.
   REF: Reference Dimension, usually without tolerance, for information purposes only.

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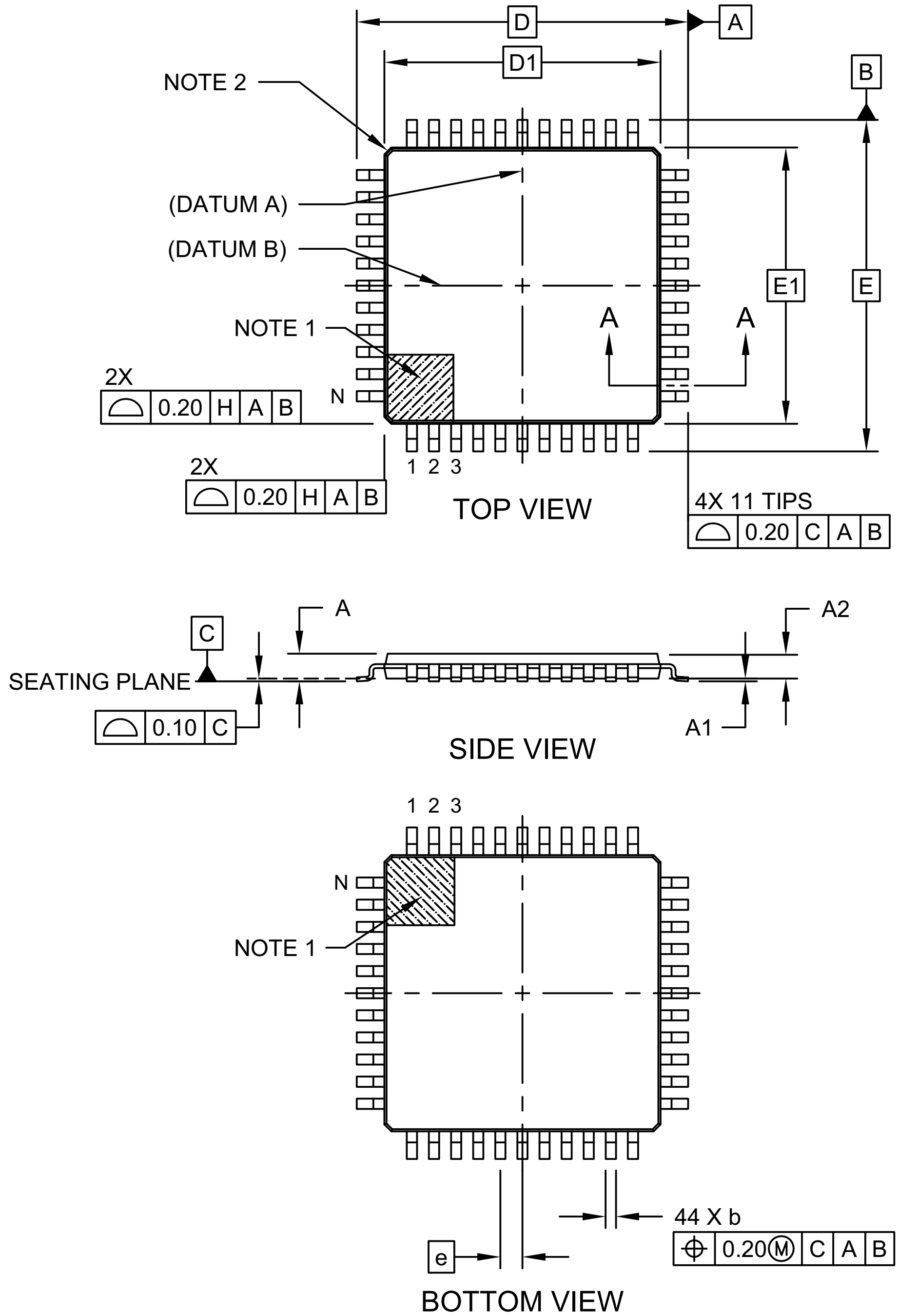
44-Lead Plastic Thin Quad Flatpack (PT) - 10x10x1.0 mm Body [TQFP]

Note:	For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



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